

Description

The 2SK3018 uses advanced trench technology

to provide excellent $R_{\text{DS}(\text{ON})\text{,}}$ low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

General Features

V_{DS} = 30V I_D =0.1A

 $R_{DS(ON)} < 2.2\Omega @ V_{GS} = 10V$

ESD Rating: HBM≥2000V

Application

Battery protection

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

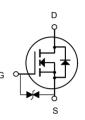
Product ID	Pack	Marking	Qty(PCS)
2SK3018	SOT-23	KN	3000

Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

Symbol	Parameter	Limit	Unit		
Vds	Drain-Source Voltage		30	V	
Vgs	Gate-Source Voltage	±20	V		
	Continuous Drain Current (Tյ =150℃)	T _A =25℃	0.1		
Ι _D		T _A =100℃	0.07	A	
Ідм	Drain Current-Pulsed (Note 1)		0.65	А	
PD	Maximum Power Dissipation	0.35	W		
Тј,Тѕтс	Operating Junction and Storage Temperature Range		-55 To 150	°C	
Reja	Thermal Resistance, Junction-to-Ambient (Note 2)		200	°C /W	







N-Channel MOSFET



Electrical Characteristics (T_A=25[°]Cunless otherwise noted)

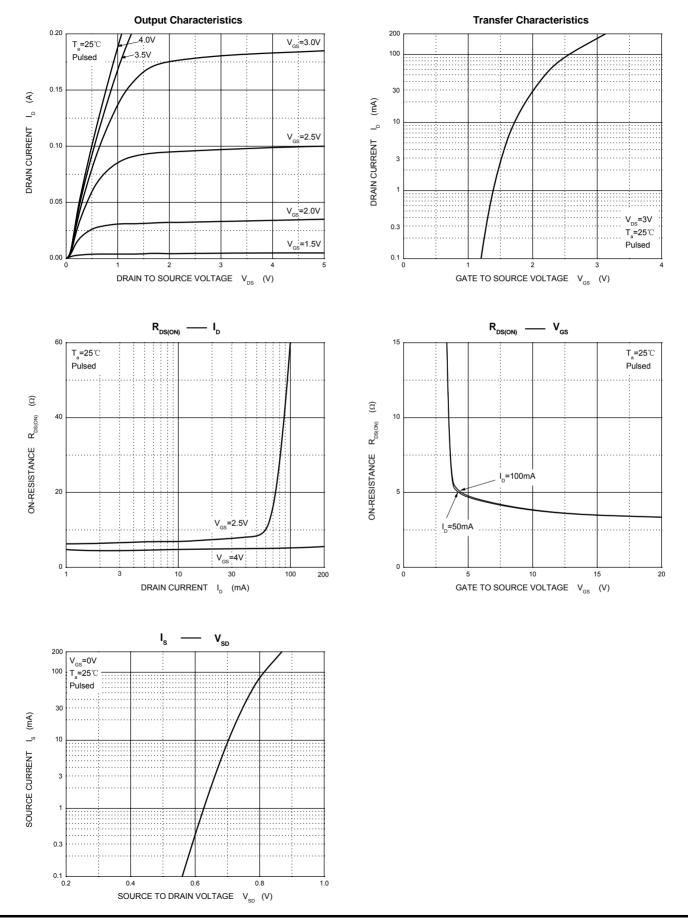
Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	Vds	Vgs = 0V, Id = 10µA	30			V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =30V,V _{GS} = 0V			0.2	μA
Gate –Source leakage current	lgss	Vgs =±20V, Vds = 0V			±2	μA
Gate Threshold Voltage	VGS(th)	V _{DS} = 3V, I _D =100µA	0.8		1.5	V
Drain-Source On-Resistance	RDS(on)	Vgs = 10V, Id =10mA		1.5	2.2	Ω
		Vgs =4.5V,Id =1mA		2	3	Ω
Forward Transconductance	gfs	Vos =3V, Io = 10mA	20			mS
Dynamic Characteristics*						
Input Capacitance	Ciss			13		pF
Output Capacitance	Coss	VDS =5V,VGS =0V,f =1MHz		9		pF
Reverse Transfer Capacitance	Crss			4		pF
Switching Characteristics*						
Turn-On Delay Time	td(on)			15		ns
Rise Time	tr	V_{GS} =5V, V_{DD} =5V,		35		ns
Turn-Off Delay Time	td(off)	I⊳ =10mA, Rg=10Ω, R∟=500Ω,		80		ns
Fall Time	tr]		80		ns

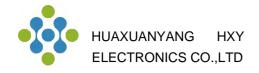
* These parameters have no way to verify.



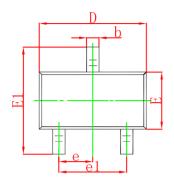
2SK3018 N-Channel Enhancement Mode MOSFET

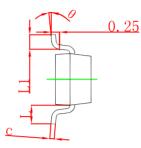
Typical Characteristics

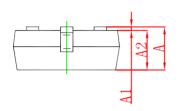




SOT-23 Package Outline Dimensions

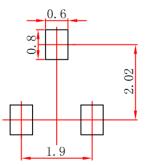






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950	0.950 TYP		7 TYP	
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



Note:

1.Controlling dimension in millimeters.

2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.



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